

L Number	Hits	Search Text	DB	Time stamp
-	18958	sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:30
-	41300	dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 13:36
-	579	(sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) same dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 15:40
-	1914720	si or silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:34
-	574	((sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) same dislocation) and (si or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 15:42
-	2256	dislocation same degree	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:23
-	81	((sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) same dislocation) and (si or silicon)) and (dislocation same degree)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 15:52
-	1417702	semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 15:55
-	746	"si.sub.1-xge" or "si.sub.1-xge.sub.x" or "si.sub.1-x ge.sub.x"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:07
-	707	"si.sub.xge" or "si.sub.xge.sub.1-x" or "si.sub.x ge.sub.1-x" or "si.sub.x ge"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:07
-	50	"si.sub.yge" or "si.sub.yge.sub.1-y" or "si.sub.y ge.sub.1-y" or "si.sub.y ge"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:07
-	132	"si.sub.1-yge" or "si.sub.1-yge.sub.y" or "si.sub.1-y ge.sub.y"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:07
-	15988	si\$1ge or ge\$1si	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:19

-	38594	(sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) or ("si.sub.1-xge" or "si.sub.1-xge.sub.x" or "si.sub.1-x ge.sub.x") or ("si.sub.xge" or "si.sub.xge.sub.1-x" or "si.sub.x ge.sub.1-x" or "si.sub.x ge") or ("si.sub.yge" or "si.sub.yge.sub.1-y" or "si.sub.y ge.sub.1-y" or "si.sub.y ge") or ("si.sub.1-yge" or "si.sub.1-yge.sub.y" or "si.sub.1-y ge.sub.y") or (si\$lge or ge\$lsi) or (silicon near2 germanium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:28
-	2432322	".degree." or ".degrees." or "-degree" or "-degrees" or degree	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:23
-	2256	dislocation same (".degree." or ".degrees." or "-degree" or "-degrees" or degree)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:23
-	177	(dislocation same (".degree." or ".degrees." or "-degree" or "-degrees" or degree)) and ((sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) or ("si.sub.1-xge" or "si.sub.1-xge.sub.x" or "si.sub.1-x ge.sub.x") or ("si.sub.xge" or "si.sub.xge.sub.1-x" or "si.sub.x ge.sub.1-x" or "si.sub.x ge") or ("si.sub.yge" or "si.sub.yge.sub.1-y" or "si.sub.y ge.sub.1-y" or "si.sub.y ge") or ("si.sub.1-yge" or "si.sub.1-yge.sub.y" or "si.sub.1-y ge.sub.y") or (si\$lge or ge\$lsi) or (silicon near2 germanium))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:24
-	38594	(sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) or ("si.sub.1-xge" or "si.sub.1-xge.sub.x" or "si.sub.1-x ge.sub.x") or ("si.sub.xge" or "si.sub.xge.sub.1-x" or "si.sub.x ge.sub.1-x" or "si.sub.x ge") or ("si.sub.yge" or "si.sub.yge.sub.1-y" or "si.sub.y ge.sub.1-y" or "si.sub.y ge") or ("si.sub.1-yge" or "si.sub.1-yge.sub.y" or "si.sub.1-y ge.sub.y") or (si\$lge or ge\$lsi) or (silicon near2 germanium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:28
-	177	(dislocation same (".degree." or ".degrees." or "-degree" or "-degrees" or degree)) and ((sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) or ("si.sub.1-xge" or "si.sub.1-xge.sub.x" or "si.sub.1-x ge.sub.x") or ("si.sub.xge" or "si.sub.xge.sub.1-x" or "si.sub.x ge.sub.1-x" or "si.sub.x ge") or ("si.sub.yge" or "si.sub.yge.sub.1-y" or "si.sub.y ge.sub.1-y" or "si.sub.y ge") or ("si.sub.1-yge" or "si.sub.1-yge.sub.y" or "si.sub.1-y ge.sub.y") or (si\$lge or ge\$lsi) or (silicon near2 germanium))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 17:48
-	189349	"90.degree." or "90 .degree." or "90-degree" or "90 degree"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 17:49
-	28	("90.degree." or "90 .degree." or "90-degree" or "90 degree") with dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 17:58

-	856	angle with dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 17:59
-	35	(angle with dislocation) and ((sige or gesi or si?ge or ge?si or silicon?germanium or germanium?silicon) or ("si.sub.1-xge" or "si.sub.1-xge.sub.x" or "si.sub.1-x ge.sub.x") or ("si.sub.xge" or "si.sub.xge.sub.1-x" or "si.sub.x ge.sub.1-x" or "si.sub.x ge") or ("si.sub.yge" or "si.sub.yge.sub.1-y" or "si.sub.y ge.sub.1-y" or "si.sub.y ge") or ("si.sub.1-yge" or "si.sub.1-yge.sub.y" or "si.sub.1-y ge.sub.y") or (si\$lge or ge\$lsi) or (silicon near2 germanium))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 17:59
-	2847	(burgers or displac\$5) adj3 vector	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:47
-	41300	dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:47
-	147	((burgers or displac\$5) adj3 vector) same dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:47
-	34912	"si.sub."\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:30
-	3614	"ge.sub."\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:30
-	19002	sige or gesi or si\$lge or ge\$lsi or silicon\$lgermanium or germanium\$lsilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 13:35
-	19804	("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$lsi or silicon\$lgermanium or germanium\$lsilicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 13:36
-	102704	gaas or gallium adj2 arsenide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:32
-	11127	"ga.sub."\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:32
-	5794	"as.sub."\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:32
-	102931	("ga.sub."\$4 near3 "as.sub."\$4) or (gaas or gallium adj2 arsenide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:33

-	619021	ge or germanium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:33
-	1915580	si or silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:34
-	169601	relax\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:35
-	2004022	intermediat\$4 or buffer\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:36
-	9063	(intermediat\$4 or buffer\$4) with ((ge or germanium) or ("ga.sub."\$4 near3 "as.sub."\$4) or (gaas or gallium adj2 arsenide)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:37
-	41332	dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:38
-	878	((intermediat\$4 or buffer\$4) with ((ge or germanium) or ("ga.sub."\$4 near3 "as.sub."\$4) or (gaas or gallium adj2 arsenide)))) and (("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$l\$si or silicon\$lgermanium or germanium\$l\$silicon))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:39
-	375	((intermediat\$4 or buffer\$4) with ((ge or germanium) or ("ga.sub."\$4 near3 "as.sub."\$4) or (gaas or gallium adj2 arsenide)))) and (("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$l\$si or silicon\$lgermanium or germanium\$l\$silicon)) and dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:39
-	374	((intermediat\$4 or buffer\$4) with ((ge or germanium) or ("ga.sub."\$4 near3 "as.sub."\$4) or (gaas or gallium adj2 arsenide)))) and (("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$l\$si or silicon\$lgermanium or germanium\$l\$silicon))) and dislocation) and (si or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:40
-	363454	strain\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:40
-	319	(((((intermediat\$4 or buffer\$4) with ((ge or germanium) or ("ga.sub."\$4 near3 "as.sub."\$4) or (gaas or gallium adj2 arsenide)))) and (("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$l\$si or silicon\$lgermanium or germanium\$l\$silicon))) and dislocation) and (si or silicon) and (relax\$6 or strain\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:56
-	1	lattice with (("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$l\$si or silicon\$lgermanium or germanium\$l\$silicon)) with isotropic\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 17:53

-	460	438/478.ccls. or 148/dig.59.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 13:34
-	19804	("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$lsi or silicon\$lgermanium or germanium\$l\$silicon)	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 13:36
-	91	(438/478.ccls. or 148/dig.59.ccls.) and (("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$lsi or silicon\$lgermanium or germanium\$l\$silicon))	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 13:36
-	41332	dislocation	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 13:36
-	37	((438/478.ccls. or 148/dig.59.ccls.) and (("si.sub."\$4 near3 "ge.sub."\$4) or (sige or gesi or si\$lge or ge\$lsi or silicon\$lgermanium or germanium\$l\$silicon))) and dislocation	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/17 13:36